		Search Text		DBs	. In
	Type Hits		I ISPAT:	US-PGPUB	200
	BRS 14			US-PGPUB	200
\$	BRS 0	(257/\$ ccls.) and ((poly adj methyl adj methacrylate) with (gate adj (insulator or insulating or insulation or dielec			200
	BRS 0	((poly adj methyl adj methacrylate) same (gate adj (insulator or insulating or insulation or dielectric)))	USPAT	US-PGPUB	200
2	BRS 0	((poly adj methyl adj methacrylate) with (gate adj (insulator or insulating or insulation or dielectric))	USPAT	US-PGPUB	200
		((photo or light) adj (responsive or sensitive)) and 257/40.ccls.	USPAT	US-PGPUB	200
7	BRS 17	("6331356" "6323309" "6271107" "6246105" "6204515" "6159779" "6060338" "5998804" "5908583" "5677545	USPAT:	US-PGPUB	200
8	BRS 2	((photo or light) adi (responsive or sensitive)) and ((polymer with (gate adi (insulator or insulating or insulation	USPAT:	US-PGPUB	200
	BRS 26			US-PGPUB	200
	BRS 1	: "20020084504"		US-PGPUB	200
11		((photo or light) adj (responsive or sensitive or sensor or sensing)) and ((semiconducting or semiconductive or			200
		((photo or light) with (responsive or sensitive or sensor or sensing)) and (((semiconducting or semiconductive			200
13	BRS 23	(alcohol with (poly adi vinyl adi phenol))	USPAT;	US-PGPUB	200
		(ancoing) with (body adj viny) and preligify: ((photo or light) adj (responsive or sensitive)) and (organic with (fet or (field adj effect adj transistor) or mosfet			200
		(polymer with channel) and (organic with (fet or (field adj effect adj transistor) or mosfet or igfet or transistor))			200
		((photo or light or image) ad (responsive or sensitive or sensor or sensing or detecting or detector)) and ((poly			200
		((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (*490			200
		((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (org			200
		((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) same (org			200
		("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene)) and (((photo o			200
		(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) with (source or drain))			200
	BRS 1			US-PGPUB	200
	BRS 1 BRS 1	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel) (("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel)	USPAI,	US-PGPUB	2000 2000
	BRS 0	(("p3ot" or "p3ot" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) same channel)		OS-PGPUB O: DERWEN	
	BRS 0	:(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or octylthiopene or hexylthiopene) and channel)		O. DERWEN	F. IDM: 200
				O. DERWEN	
				US-PGPUB	200
		(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and channel))			200
				US-PGPUB	200
				US-PGPUB	200
				US-PGPUB	200
				US-PGPUB	2003
	BRS 2	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) with (mosfet o			2003
	BRS 1	(("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene)) and ((organic	USPAT;	US-PGPUB	2000
36	BRS 1	(photo adi transistor) and ((organic adi (mosfet or igfet or fet or transistor or tft or (thin adi film adi transistor) o	USPAT;	US-PGPUB	2000
		(photo adi transistor) and (organic with (mosfet or igfet or fet or transistor or tft or (thin adi film adi transistor)	USPAT;	US-PGPUB	2003
				US-PGPUB	2003
				US-PGPUB	2003
	BRS 2	(257/462.ccls.) and (organic.clm.) ("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and (257/462.c	USPAT:	US-PGPUB	2003
4:	BRS 1	: ("p3ot" or "p3ot" or "p3at" or (alkyl adi thiopene) or (octyl adi thiopene) or (hexyl adi thiopene) $(257/462 c^2)$	LISPAT.	US-PGPUB	2003

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42 BRS 6		USPAT;	US-PGPUI	3	2003/0
43 BRS 2	((257/\$.ccls.) or (438/\$.ccls.)) and offt (organic adj substrate), and (((photo or light or image) adj (responsive or sensitive or sensor or sensing or con	USPAT:	US-PGPUI	В :	2003/0
44 BRS 36	(organic with (transistor or fet or mosfet or infet or misfet) with application with light)	USPAT:	US-PGPUI	5	2003/0
45 BRS B	(photosensing adi (transistor or fet or mosfet or infet or misfet))	USPAT:	US-PGPUI	В	2003/0
46 BRS 24	((display adi device) with (photo\$1transistor or (photo adi transistor))	USPAT;	US-PGPUI	5	2003/0
47 BRS 10	(display same (photo\$1transistor or (photo adi transistor))) and (257/\$.ccls.)	USPAT;	US-PGPUI	5	2003/0
48 BRS 7	(funavama and satoshi) in.	USPAT;	US-PGPU	В	2003/0
49 BRS 14	(hiraj and katsura).in.	USPAT;	US-PGPU	5	2003/0
50 BRS 12	(equchi and toshiva).in.	USPAT;	US-PGPU	3	2003/(
51 BRS 0	((organic add (tft or thin\$1film or (thin add film)) add (mosfet or igfet or transistor or fet or (field add effect)))) a	USPAT;	US-PGPU	<u> </u>	2003/
52 BRS 4	(organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/431.ccls.)	USPAI;	US-PGPU	В	2003/
153 BRS 6	(organic.ti.) and (257/431.ccls.) ((organic.ab.) and (257/431.ccls.)) not ((organic.ti.) and (257/431.ccls.))	USPAT,	US-PGPU	B	2003/0
154 BRS 12	((organic ab.) and (257/431 ccis.)) not ((organic ti.) and (25//431 ccis.))	USPAT,	US-PGPU	B	2003/(2003/(
155 BRS 17	(organic.ab.) and (257/431.cds.) (organic.ab.) and (257/462.cds.)	USPAI,	US-PGPU		2003/(2003/(
56 BRS 2	(organic ab.) and (25//462 ccis.)	USPAI,	US-PGPU	<u> </u>	
57 BRS 1	(organic ti.) and (257/462 ccls.) ((organic adj. (mosfet or igfet or transistor or fet or (field adj.effect) or tft))) and (phototransistor or photo\$1	EDO: II	DO-DERWI	FNT: IRM	2003/
58 BRS 0	((organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft))) and ((light or photo) adj (sensin	EDO: II	DERWIN	ENT IRM	2003/
59 BRS 0	((display adj device) with ((light or infrared or radiation or photo)adj (sensing or sensitive or responsive or sens	LICDAT	US-PGPIII	R :	2003/(
60 BRS 19	((display adj device) with (flight of limated of radiation of photo)adj (sensing of sensitive of responsive of sensitive of sensitive of responsive of sensitive of responsive of sensitive of sensitive of responsive of sensitive of responsive of sensitive of sensitive of sensitive of responsive of sensitive of sensi	LISPAT	US-PGPU	Ř	2003/0
			US-PGPU		2003/0
63 BRS 5	(25//462.ccls.) and organic (photo adj transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adj fil				2003/0
64 BRS 6	((photo or light) adj (responsive or sensitive or sensor or sensing)) and ((semiconducting or semiconductive or	USPAT	US-PGPU	В	2003/0
LOC DDC C	"((abeta as light) adi (sacapanèna as cancitina as cancas as cancina)) and ((camicanductina as camicanductina as	ILICDAT:	I IS-PGPI II	a :	2003/0
SS BRS 2	(organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.) (organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.) (display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.) (display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.) (organic adj (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and ((light or infrared or radiation))	USPAT:	US-PGPU	В	2003/0
67 BRS 2	(organic with (mosfet or igfet or transistor or fet or (field adj effect))) and (257/462.ccls.)	USPAT:	US-PGPU	В	2003/0
68 BRS 7	(display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.)	USPAT;	US-PGPU	В	2003/0
69 BRS 7	(display with (photo\$1transistor or (photo adj transistor))) and (257/\$.ccls.)	USPAT:	US-PGPU	B	2003/0
70 BRS 10	(organic adj. (mosfet or igfet or transistor or fet or (field adj. effect) or tft).) and ((light or infrared or radiation	USPAT;	US-PGPU	В	2003/0
HE BKS 3	(Innote of light of image) and fresponsive of sensitive of sensor of sensing of detecting of detector) and (tord)	RUSPAI.	. 03-FGF01	D 14	2003/0
72 BRS 11	(organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (sensing or sensitive or resp.	EPO; JI	PO: DERW	ENT; IBM	2003/(
73 BRS 11	(organic adj. (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (sensing or sensitive or resp.	EPO; J	PO: DERW	ENT: IBM	2003/0
74 BRS 5	(photo adj transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adj fil	USPAT;	US-PGPU	3	2003/
75 BRS 5	(photo adj transistor) and (organic with (mos\$1fet or ig\$1fet or mis\$1fet or fet or transistor or tft or (thin adj fil	USPAT;	US-PGPUI	<u> </u>	2003/
176 BRS 15	(organic with channel) and (((photo or light or image) adj (responsive or sensitive or sensor or sensing or cond	USPAT:	US-PGPU	<u> </u>	2003/0
	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (orga	USPAT	US-PGPUI	3	2003/(2003/(
78 BRS 2	((organic adj (mosfet or igfet or fet or transistor or tft or (thin adj film adj transistor) or (thin\$1 film adj transistor)				2003/0 2003/0
	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (orga ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((org	LICEAT	US-FGFUI		2003/0 2003/0
80 BRS 3 81 BRS 2	((pnoto or light or image) and (responsive or sensitive or sensing or detecting or detector)) and ((org., ((organic adj (mosfet or igfet or fet or transistor or tit or (thin adj film adj transistor) or (thin\$1film adj transistor)	LISPAT	IIC PARII	ž	2003/0 2003/0
PD DRO 2	((organic adj (mostet or ignet or fet or transistor of the organic adj (min adj transistor) of (thing film adj transistor) ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (org	LICDAT	LIS POPUL		2003/0
83 BRS 8	indumer and (257/462 ccls.)	LICEAT	US-PGPUI	<u> </u>	2003/0

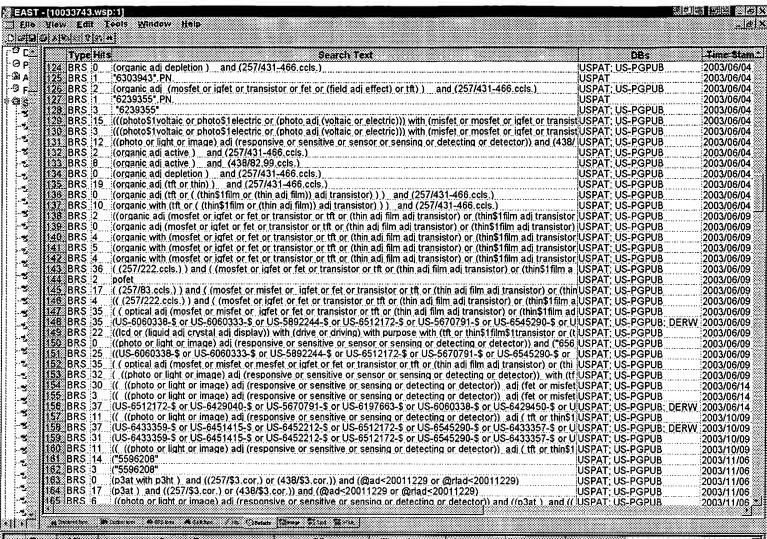
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83 BRS 8		USPAT: U		2003/0
	((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) same (org	USPAT; U	S-PGPUB	2003/0
85 BRS 4	(organic with (mosfet or igfet or transistor or fet or (field adi effect) or tft)) and (257/431.ccls.)	USPAT; U	S-PGPUB	2003/0
86 BRS 8	polymer and (257/462.ccls.) (organic with (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (257/431.ccls.)	USPAT; U	S-PGPUB	2003/0
87 BRS 4	(organic with (mosfet or igfet or transistor or fet or (field adj effect) or tft)) and (257/431.ccls.)	USPAT; U	S-PGPUB	2003/0
CL CADIMIDAN	HOLOGING MINI CHANNEN AND (HONOLO OF HOUR OF HUNDLE) AND HESPONSIVE OF SENSIVE OF SENSON OF SENSING OF COINCE	03FA1, 0	3-F G F U U	2003/0
89 BRS 12	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and channel)	USPAT; U	S-PGPUB	2003/0
90 BRS 15	(organic with channel) and (((photo or light or image) adj (responsive or sensitive or sensor or sensing or cond	USPAT; U	S-PGPUB	2003/0
91 BRS 26	((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) and (((25.	USPAT; U	S-PGPUB	2003/0
	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene))and channel)	USPAT; U	S-PGPUB	2003/0
93 BRS 1	"20020084504" ((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) and (((25	USPAT; U	S-PGPUB	2003/0
	((25))) and (((25)) or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)	USPAT; U	S-PGPUB	2003/0
95 BRS 8	(((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (or			2003/0
96 BRS 16	(((semiconducting or semiconductive or semiconductor) adi polymer) and ((source or drain) with polymer)) and	USPAT; U	S-PGPUB	2003/0
97 BRS 21	(((semiconducting or semiconductive or semiconductor) adi polymer) and ((source or drain) with polymer)) and	USPAT; U	S-PGPUB	2003/0
98 BRS 2	((organic with pixel) and (257/\$.ccls.)) and (photo\$1transistor or (photo adj transistor))	USPAT; U	S-PGPUB	2003/0
99 BRS 13	(organic with (photo\$1transistor or (photo adj transistor)))	USPAT; U	S-PGPUB	2003/0
100 BRS 9	(organic with (photo\$1transistor or (photo adi transistor)))	EPO; JPO	; DERWENT; IBM	2003/0
101 BRS 5	((forganic with pixel) and (257(\$.ccls.)) and (photo\$1transistor or (photo adj transistor)) (organic with (photo\$1transistor or (photo adj transistor))) (organic with (photo\$1transistor or (photo adj transistor))) (organic with (photo\$1transistor or (photo adj transistor))) ((display adj device) with ((light or infrared or radiation or photo)adj (sensing or sensitive or responsive or sens	EPO; JPO	: DERWENT: IBM	2003/0
113UZ BRS 4	:"U1259563"	JPO: DEK	VVENI	2003/0
103 BRS 6	5355235	USPAI, U	3-FGFUD	2003/0
104 BRS 9	(((photo of light of image) and (responsive of sensitive of sensor of sensing of detecting of detector)) same (of	USPAI, U	3-FGFUB	2003/0
	(((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) same (or	USPAT; U	S-PGPUB	2003/0
106 BRS 0	((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or	USPAT, U	S-PGPUB	2003/0
107 BRS 0	((photo or light or image) adi (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or	USPAT; U	S-PGPUB	2003/0
108 BRS 39	((((organic or polymer or polymeric) with depletion) and (tft or fet or (field adj effect) or mosfet or igfet or tran	USPAT; U	S-PGPUB	2003/0
109 BRS 39	(((organic or polymer or polymeric) with depletion) and (tft or fet or (field adj effect) or mosfet or igfet or tran	USPAT; U	S-PGPUB	:2003/0
110 BRS 2		USPAT; U		2003/0
111 BRS 4	"5232631" and (257/431-466.ccls.) (organic adj active adj layer) and (tft or fet or (field adj effect) or mosfet or infet or transistor) and (257/431-4	USPAT; U	S-PGPUB	2003/0
112 BRS 2	(organic adjactive adjayer) and (Iff or fet or (field adjeffect) or mostet or infet or transistor) and (25//431-4	USPAT; U	S-PGPUB	2003/0
1113 BRS 19	(organic adj. (tft or thin\$1film or (thin adj film))) and (257/431-466.ccls.)	USPAT; U	S-PGPUB	2003/0
114 BRS 0	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (((or	USPAT; U	S-PGPUB	2003/0
115 BRS 3	((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((org	USPAT; U	S-PGPUB	2003/0
116 BRS 19	((organic adj. (tft or thin\$1film or (thin adj film))) and (257/431-466.ccls.)) and (photo or light or image)	USPAT; U	S-PGPUB	2003/0
117 BRS 0	("5892244" "6060333" "6060338") and (257/431-466.ccls.) ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ("589	USPAT; U	S-PGPUB	2003/0
				2003/0
119 BRS 17	"5892244" "6060333" "6060338"	USPAT; U	S-PGPUB	2003/0
		USPAT; US		2003/0
121 BRS 0	(*6569707**	USPAT; U	S-PGPUB	2003/0
122 BRS 10	(organic adi. (mosfet or igfet or transistor or fet or (field adi effect) or ttt)) and ((light or infrared or radiation (organic adi. (semiconductive or semiconducting or semiconductive)) and (257/431-466.ccls.)	USPAT; US	S-PGPUB	2003/0
123 BRS 7	(organic adj. (semiconductive or semiconducting or semiconductive)) and (257/431-466.ccls.)	USPAT; US	S-PGPUB	2003/0
124 BRS 0	(organic adi depletion.) and (257/431-466 ccls.)	USPAT: US	S-PGPUB	2003/0
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165 BRS 6 ((photo or light o	image) adi (responsive or sensitive or sensin	a or detecting or detector)) and ((n		200
166 BRS 1 20020084504	intage, adi tresponsive or sensitive or sensiti	g of detecting of detector)) and ((b	USPAT: US-PGPUB	200
167 BRS 0 "2002/0084504"			USPAT: US-PGPUB	200
168 BRS 14 ("5596208"			USPAT: US-PGPUB	200
169 BRS 2 ("5596208"			USPAT: US-PGPUB	200
179 BRS 23 ((photo or light of	image) adi (responsive or sensitive or sensin	a or detectina or detector or senso		200
171 BRS 8 ("5331138"			USPAT: US-PGPUB	200
172 BRS 0 ((photo or light o	image) adi (responsive or sensitive or sensin	g or detecting or detector or senso	r)) and ((" USPAT; US-PGPUB	200
173 BRS 1 ((photo or light o	image) adj (responsive or sensitive or sensin	g or detecting or detector or senso	r)) and ((pol USPAT; US-PGPUB	200
174 BRS 12 (((photo or light o	r image) adi (responsive or sensitive or sensi	ng or detecting or detector or sense	or)) with (dri USPAT; US-PGPUB	200
175 BRS 1 ("0528662" "05	75187" "0716459" "0717445" "0786820"	"2360177" 90/08402)	iEPO	200
176 BRS 6 ("528662" "575	187" "716459" "717445" "786820" "236	0177" 90/08402)	EPO	200
177 BRS 1 ("528662" "575	187" "716459" "717445" "786820" "236	0177" 90/08402) and ((photo or	r light or ima EPO	200
178 BRS 15 ("528662" "575	187* "716459" "717445" "786820" "236		DERWENT	200
	187" "716459" "717445" "786820" "236)177" 90/08402) and organic	DERWENT	200
180 BRS 1 ("9008402")			DERWENT	200
181 BRS 1 6326640.pn.			USPAT; US-PGPUB	200
182 BRS 4 ((photo or light o	image) adi (responsive or sensitive or sensin	g or detecting or detector)) and ((U	IS-6433359-USPAT: US-PGPUB	200
	e) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @nad<200112	29) USPAT; US-PGPUB EPO: DERWENT	200 200
184 BRS 3 "9954936"	image) adi (responsive or sensitive or sensin	a ar datastian ar datastan) and (60	COCCIO ON VICTOR LIC DODIE	200
185 BRS 0 ((photo or light o	or image) adj (responsive or sensitive or sensit or image) adj (responsive or sensitive or sens	g or detecting or detector)) and too	to or (thin a ILISPAT: US-FGFUB	200
187 BRS 1 ((photo or light o	r image) adj (responsive of sensitive of sensi r image) adj (responsive of sensitive of sensin	a or detecting or detector)) and (66	S03130 pp \ IISPAT: IIS PGPIIR	200
168 BRS 6 (p3at) and p3ht	and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ac	<20011229 or @dad<20011229\	USPAT: US-PGPUB	200
169 BRS 32 ("20010052597"	and ((257745.001.) of (450745.001.7) and (@at	1720011225 01 021104 7200112257	USPAT: US-PGPUB	200
	I (US-20020190253-A1.DID. and (((((photo o	r light or image) adi (responsive or	sensitive or USPAT US-PGPUB	200
191 BRS 0 (p3at or p3ht) and	1 ((257/290 cor) and (@ad<20011229 or @r	lad<20011229)	USPAT: US-PGPUB	200
192 BRS 2 (organic with (fet	l ((257/290.cor.) and (@ad<20011229 or @r or misfet or mosfet or igfet or mesfet or (field	adi effect) or transistor or tft or thi	n\$1film\$1tra USPAT: US-PGPUB	200
193 BRS 6 (organic with (fet	or misfet or mosfet or iafet or mesfet or (field	adi effect) or transistor or tft or this	n\$1film\$1tra iUSPAT: US-PGPUB	200
194 BRS 3 (organic with (fet	or misfet or mosfet or iafet or mesfet or (field	adi effect) or transistor or tft or this	n\$1film\$1tra USPAT: US-PGPUB	200
195 BRS 9 "5693977" and	(@ad<20011229 or @rlad<20011229)		USPAT: US-PGPUB	200
198 BRS 4 ((nhoto or light of	r image) adi (responsive or sensitive or sensin	a or detectina or detector)) and (('	'200100525 iUSPAT: US-PGPUB	200
197 BRS 6 ((photo or light o	image) adj (sensor)) and (("20010052597" image) adj (responsive or sensitive or sensin	***************************************	USPAT: US-PGPUB	200
198 BRS 1 ((photo or light o	r image) adi (responsive or sensitive or sensin	g or detecting or detector)) and (66	03139.pn.) USPAT; US-PGPUB	200
199 BRS 6 (organic with (fet	or misfet or mosfet or igfet or mesfet or (field	adi effect) or transistor or tft or thi	n\$1film\$1tra USPAT; US-PGPUB	200
200 BRS 0 ((organic with (fel	or misfet or mosfet or igfet or mesfet or (field	l adj effect) or transistor or tft or th	in\$1film\$1tr USPAT; US-PGPUB	200
201 BRS 4 ((photo or light o	image) adi (responsive or sensitive or sensin	g or detecting or detector)) and (('	200100525 USPAT; US-PGPUB	200
	ive or light\$1responsive or image\$1responsive			200
203 BRS 6 (organic with (fet	or misfet or mosfet or iafet or mesfet or (field	adi effect) or transistor or tit or thi	n\$1πim\$1tra USPA1; US-PGPUB	200
204 BRS 23 (((photo or light of	or image) adj (responsive or sensitive or sensi r US-6451415-\$ or US-6452212-\$ or US-6512	ng or detecting or detector or sense	OF)) WITH OF QUOPAL US-PGPUB	200
	1 UO-0431415-\$ 01 UO-0432212-\$ 01 UO-6512	11/2-3 OF US-634329U-3 OF US-643	USPAT: US-PGPUB	200 200
206 BRS 31 ("20030038590"		4	JUSPAT, US-PGPUB	ZUU

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	OR BR	5 31	("20030038590"	USPAT	US-PGPUB	2003/
Н	07 BR	5 30	: (((about or limit or image) and (responsive or sensitive or sensing or delecting or delector or sensor)) with ord	USPAT	US-PGPUB	2003/
	08 BR		*9925028*	DERWE	NT	2003/
H	09 BR		**9925028**	DERWE	ENT	2003/
H	10 BR	5 27	polyparaphenylenevinylene with organic	USPAT:	US-PGPUB	2003/
	11 BR		20010052597* ((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and (("2	USPAT	US-PGPUB	2003/
	12 BR		((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and ((2	USPAT		2003/
Ш	13 BR	<u>5. [1</u>			US-PGPUB	2003/
	14 BR	5 5	((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and (('2	USPAT	US-PGPUB	2003/
	15 BR	2 :15	(((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor)) and (("2	LICEAT	US-PGPUB US-PGPUB	2003/
H	10 BK	0 15	"20020084504" and (high adi dielectric) ((photo or light or image) adi (responsive or sensitive or sensing or detecting or detector or sensor)) and (("2	LICOAT	US-FORUD	2003/
H	HODE	2 112	: ((photo or light or image) adj (responsive or sensitive or sensing or detecting or detector or sensor), and ((2 : (p3ht)	LISPAT		2003/
Н	19 BR	20	(p3ht) with light			2003/
H	20 BR	2	(p3ht)and ("20020017612" "6303943").did.	LISPAT	US-PGPUB	2003/
	21 BR		poly\$1*3-hexythiophene* with mobility	USPAT	US-PGPUB	2003/
	22 BR		pol/\$1"3-hex/l thiophene" with mobility	USPAT	US-PGPUB	2003/
	23 BR		:n3ht with mobility	USPAT:	US-PGPUB	2003/
	24 BR			USPAT	US-PGPUB	2003/
H	25 BR	5 27	(poly adi hexylthiophene) (gold with transparent with "100 nm")	USPAT	US-PGPUB	2003/
	26 BR	S :1	glass and (6197663.pn.)	USPAT:	US-PGPUB	2003/
11	27 BR	5 0	(p3ht with acceptor)	USPAT:	US-PGPUB	2003/
	28 BR	5 2	(p3ht with doped)	USPAT	US-PGPUB	2003/
	29 BR	5 14	((glass adj substrate) with polvimide) and tft and (257/\$3.cor.)	USPAT	US-PGPUB	2003/
	30 BR	5 26	polyimide with transparent with micron	USPAT	US-PGPUB	2003/
	31 BR	5 ‡1	(polyimide with transparent with nm) and ((257/\$3,cor.) or (438/\$3,cor.))	USPAT	US-PGPUB	2003/
	32 BR	5 35	polyimide with transparent with nm not wavelength	USPAI	US-PGPUB	2003/
	33 BR	5.11			PO; DERWENT; IBM	
H,	34 BR	5 33	(mylar with flexible) and ((257/\$3.cor.) or (438/\$3.cor.)) ((polymethyl adj methacrylate) with (gate adj (dielectric or insulator or insulating or insulation)))	USPAT		2003/
Н	35 BR				US-PGPUB	2003/
						2003/
	38 BR				US-PGPUB ERWENT	2003/
	39 BR		"qb9803087"	FPO D	COVEYCAIT	2003/
	40 BR		9721808.5	EPO D	ERWENT	2003/
	41 BR		: 97218085"	EPO D	ERWENT	2003/
	42 BR		gb097218085*	EPO: D	ERWENT	2003/
	43 BR		"gb09721808"		ERWENT	2003/
H,	44 BR	5 0	GB002330451	EPO; D		2003/
	45 BR		: "002330451"	EPO: D	ERWENT	2003/
H	46 BR	S 3	: #2000 <i>1E1</i> #	EPO; D	ERWENT	2003/
11	47 BR	5.6	2330451 (((oolvmethyl adi methacrylate) with (gate))) and ((257/\$3 cor.) or (438/\$3 cor.))	USPAT:	US-PGPUB	2003/

247 248	Type Hits BRS 6				
		:(((polymethyl adj methacrylate) with (gate))) and ((257/\$3.cor.) or (438/\$3.cor.))	USPAT:	US-PGPUB	2003/1
740	BRS 0	(nolvimide with (dielectric adi constant)) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @rlad<2	USPAT;	US-PGPUB	2003/1
	BRS :25	(nolyimide with (dielectric adj constant)) and ((257/\$3.cor.) or (438/\$3.cor.)) and (@ad<20011229 or @rlad<	USPAT:	US-PGPUB	2003/1
250	BRS 1	6480577.pn, and polyimide	USPAT;	US-PGPUB	2003/1
251	BRS 7	:((pmma) with (gate adi (dielectric or insulator or insulating or insulation)))	USPAT;	US-PGPUB	2003/1
252	BRS 6	:((alcohol) same (gate adj (dielectric or insulator or insulating or insulation))) and (polyviny) with alcohol)	USPAT;	US-PGPUB	2003/1
253	BRS 4	((alcohol) with (gate adj (dielectric or insulator or insulating or insulation))) and (polyvinyl with alcohol)	USPAT;	US-PGPUB	2003/1
	BRS 2			US-PGPUB	2003/1
255	BRS 3	((pva) with (gate adi (dielectric or insulator or insulating or insulation)))	EPO; JP	O; DERWENT; IBM	1 2003/1
256	BRS 5	(polymer with (pate adj (dielectric or insulator or insulating or insulation))) same (polymer with (pva or alcohol	USPAT:	US-PGPUB	2003/1
257	BRS 16	((polymer with (gate adi (dielectric or insulator or insulating or insulation)))) and (polymer with (pva or alcohol))	USPAT;	US-PGPUB	2003/1
258		((polymer with (gate adj (dielectric or insulator or insulating or insulation)))) and (polymer with (pmma))) and (:2003/1
				US-PGPUB	2003/1
260	BRS 0	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and (pmma	USPAT;	US-PGPUB	2003/1
	BRS 0	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and ((pva o	USPAT;	US-PGPUB	2003/1
262	BRS 4	((polymer with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20011229)) and ((pva o	USPAT;	US-PGPUB	2003/1
263	BRS 19	((pva or alcohol or pmma) with tft) and (@ad<20011229) ((photo adj resist) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or re	USPAT;	US-PGPUB	2003/1
		((photo adj resist) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or re	USPAT;	US-PGPUB	2003/1
	BRS 0	(((poly\$1vinyl)) with tft) and (@ad<20011229)	USPAT;	US-PGPUB	2003/1
	BRS 6	(((poly adj vinyl)) with tft) and (@ad<20011229) ((poly adj vinyl) with (gate adj (dielectric or insulator or insulating or insulation)) not (cover or covered or remo	USPAT:	US-PGPUB	2003/1
	BRS 0	((poly adi vinyl) with (gate adi (dielectric or insulator or insulating or insulation)) not (cover or covered or remo	USPAT;	US-PGPUB	2003/1
	BRS 2			US-PGPUB	2003/1
				US-PGPUB	2003/1
				US-PGPUB	2003/1
	BRS 5			US-PGPUB	2003/1
14/4	BRS 13			US-PGPUB	2003/1
	BRS 11	(('4021835'	USPAT:	US-PGPUB	2003/1
	BRS 2	((poly\$1 viny1) with gate) and (@ad<20011229) and (257/40.ccls.)	USPAT	US-PGPUB	2003/1
	BRS 19	((poly\$1vinyl) adj alcohol) and (@ad<20011229) and (257/40.ccls.)	USPAT;	US-PGPUB	2003/1
				US-PGPUB	2003/1
	BRS 15				2003/1
	BRS 27	(inorganic adj (dielectric or insulator or insulating or insulation)) and (@ad<20010102) and (257/40.ccls.) (inorganic with (glass adj resin)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	LICEAT.	US-FORUD	2003/1
	BRS 1		LICEAT.	US-PGPUB	2003/1
	BRS 12 BRS 10	: (organic with (glass adj resin)) and (@ad<20010102) and ((257/\$5.cor.) or (456/\$5.cor.) : (inorganic with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and (257/4			2003/1
1401	BRS 35	(conorganic with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and (257/4 (inorganic with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and ((257/4))			2003/1
	BRS 0	(configuration with (gate adj (defecting or insulator or insulator)) and (wad~20010102) and ((257) (inorganic with (dielectric or insulator or insulating or insulation) with easier) and (wad~20010102) and ((257)	LICEAT.	HIS DODIN	2003/1
	BRS 5	((257)): (inorganic with (dielectric of insulator of insulator) with easier) and ((260-20010102) and ((257)): (inorganic adj gate) and ((260-20010102) and ((257)); (257)); (257)	USPAT.	IIS DODIIR	2003/1
	BRS 8	: (inorganic adjigate) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.)) : (inorganic adjigate) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	LISPAT	US-PGPUB	2003/1
		: (inorganic adjigate) and (@ad~20010102) and ((257/35.col.) of (450/35.col.)) :((inorganic with (gate adj (dielectric or insulator or insulating or insulation))) and (@ad<20010102) and ((257/			2003/1
		((silicon adi dioxide) with (gate adi (dielectric or insulator or insulating or insulation)) with simple) and (@ad<2			2003/1
287	DK 2 III				

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Type Hits	Search Text		DBs	-Time
288 BRS 0 ((silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with cheap) and (@ad<2			2003
289 BRS 4 ((silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with cost) and (@ad<20	USPAT:	US-PGPUB	2003
	(silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with ease) and (@ad-20			2003
	(silicon adj dioxide) with (gate adj (dielectric or insulator or insulating or insulation)) with simpler) and (@ad<			2003
	("sio.sub.2") with (gate adi (dielectric or insulator or insulating or insulation)) with simpler) and (@ad<20010			2003
293 BRS 2 (("sio.sub.2") with (gate adj (dielectric or insulator or insulating or insulation)) with cost) and (@ad<20010102	USPAT;	US-PGPUB	2003
	inorganic with (dielectric or insulator or insulating or insulation) with property) and (@ad<20010102) and ((2			2003
295 BRS 0 (inorganic with (dielectric or insulator or insulating or insulation) with simpler) and (@ad<20010102) and ((25	USPAT,	US-PGPUB US-PGPUB	2003 2003
295 BRS 0 (((poly\$1vinyl) adj alcohol) with tft) and (@ad<20011229) buckminsterfullerene) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	USPAT.	US-PGPUB	2003
297 BRS 19 (buckminsterfullerene) and (@ad<20010102) and ((257/53.cor.) or (436/\$3.cor.)) buckminsterfullerene with (acceptor)) and (@ad<20010102) and tft	HISPAT.	HS POPUR	2003
299 BRS 7 (buckminsterfullerene with (acceptor)) and (@ad<20010102) and the buckminsterfullerene with (acceptor)) and (@ad<20010102)	USPAT	US-PGPUR	2003/
300 BRS 10 (channel with (acceptor) with greater) and (@ad<20010102)	USPAT	US-PGPUR	2003
301 BRS 30 (channel with (acceptor) with more) and (@ad<20010102)	USPAT	US-PGPUB	2003
302 BRS 24 (channel with (acceptor)) and (@ad<20010102) and tft	USPAT:	US-PGPUB	2003
303 BRS 18 (buckminsterfullerene) and (@ad<20010102) and (25//40.ccls.)	IUSPAT:	US-PGPUB	2003
304 BRS 2 (buckminsterfullerene same channel) and (@ad<20010102) ((titanium adi dioxide) or "tio.sub.2") with acceptor) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.	USPAT:	US-PGPUB	2003
305 BRS 3 (((titanium adj dioxide) or "tio.sub.2") with acceptor) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.	USPAT:	US-PGPUB	2003
1306 BRS 0 (((titanium adj dioxide) or "tio.sub.2") with current) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))	USPAT;	US-PGPUB	2003
307 BRS 14 ((photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and ((par	USPAT:	US-PGPUB	:2003
	(photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) with poly			2003
309 BRS 0 (US-PGPUB	2003
310 BRS 0 (buckminsterfullerene) and ((((photo or light or image) adi (responsive or sensitive or sensor or sensing or de	USPAT;	US-PGPUB	2003
	photo or light or image) adj (responsive or sensitive or sensor or sensing or detecting or detector)) and (@ad			2003
312 BRS 19 (p			US-PGPUB	2003/
313 BRS 29 ((314 BRS 0 (p	photo adj (fet or transistor)) and (@ad<20010102) and ((257/53.cor.) or (438/\$3.cor.)) and (sensitivity with	USPAT.	US-PGPUB	2003
315 BRS 0 ((hoto adi (fet or transistor)) and (@ad<20010102) and (257/40.cor.) light adi sensitive) with (fet or transistor)) and (@ad<20010102) and (257/40.cor.)	USPAT.	US-PGPUB	2003/
316 BRS 5 ((photo adj (fet or transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (sensitivity with	LICDAT	US-FGFUB	2003
	(light adj sensitive) with (fet or transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (sensitive)			2003
	(light adj sensitive) with (let of transistor)) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))) and (s			2003
	photo adj (fet or transistor)) with sensitivity) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))			2003
		USPAT:	US-PGPUB	2003/
321 BRS 2 (("p3ot" or "p3ot" or "p3at") with (source or drain))	USPAT:	US-PGPUB	2003/
322 BRS 2 (("p3ot" or "p3ot") with (source or drain))		US-PGPUB	2003/
#323⊗BRS:0 (n	p3ot with light) and (@ad<20010102)		US-PGPUB	2003/
1324 BRS 3 (1	p3ot same light) and (@ad<20010102)	USPAT:	US-PGPUB	2003/
325 BRS 8 (p3ot and light) and (@ad<20010102)		US-PGPUB	2003/
326 BRS 0 p	oly\$1"3-octyfthiophene" and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))		US-PGPUB	2003/
327 BRS 18 (()	light adj sensor) with sensitivity) and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.))		US-PGPUB	2003/
328 BRS 9 (1			US-PGPUB	2003/
329 BRS 6 (1	oolv adi "3-octvfthiophene") and (@ad<20010102)	EPO: JF	O: DERWENT: I	BM:2003/

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329 BRS 6	:(poly adj "3-octylthiophene") and (@ad<20010102)	EDO: II	DO: DEDMEN	VT: IBM 2003
330 BRS 2	1 Duy and (@ad-20010102) and ((257)\$3 cor.) or (438)\$3 cor.))	LICDAT	US-PGPUB	2003
331 BRS 5	p3ot and (@ad<20010102) and ((257/\$3.cor.) or (438/\$3.cor.)) .((("3-octylthiophene") and (@ad<20010102)) and semiconductor) not (((poly adi "3-octylthiophene") and (@	LISPAT	LIS-PGPLIR	2003
332 BRS 0	p3ot and (@ad<20010102)	FPO: II	PO DERWEN	VT: IBM 2003
333 BRS 1	**6331356* and transducer	LISPAT	US-PGPUB	2003
334 BRS 0			US-PGPUB	.0000
335 BRS 1				
336 BRS 6	."6331356" and octylthiophene .((("octylthiophene") and (@ad<20010102)) and semiconductor) not (((("3-octylthiophene") and (@ad<2001	USPAT	US-PGPUB	2003
337 BRS 21	(sensor and octylthiophene) and (@ad<20010102)	USPAT	US-PGPUB	2003
338 BRS 6	(sensor and octylthiophene) and (@ad<20010102) ((sensor and octylthiophene) and (@ad<20010102)) not (((("octylthiophene") and (@ad<20010102)) and se	USPAT:	US-PGPUB	2003
	sensor and octythiophene	USPAT	US-PGPUB	2003
340 BRS 10	:(257/40.ccls.) and octylthiophene			2003
341 BRS 10	(257/40.ccls.) and octy\$1thiophene	USPAT:	US-PGPUB	2003
342 BRS 0	:((257/40.ccls.) and octyl\$1thiophene) not ((257/40.ccls.) and octylthiophene)	USPAT:	US-PGPUB	2003
343 BRS 8	(257/40.ccls.) and (thiophene same octyl)		US-PGPUB	2003
344 BRS 6	:((257/\$3.cor.) or (438/\$3.cor.)) and (thiophene same octvl)	USPAT:	US-PGPUB	2003
345 BRS 10	(257/40.ccls.) and octvl\$1thiophene	USPAT:	US-PGPUB	2003
346 BRS 1	((257/\$3.cor.) or (438/\$3.cor.)) and poly\$1octyl\$1thiophene	USPAT:	US-PGPUB	2003
347 BRS 1	((257/\$3.cor.) or (438/\$3.cor.)) and poly adj octyl adj thiophene	USPAT;	US-PGPUB	2003
348 BRS 1	:((257/\$3.cor.) or (438/\$3.cor.)) and (poly adj octyl adj thiophene)	USPAT:	US-PGPUB	2003
349 BRS 4	((257/\$3.cor.) or (438/\$3.cor.)) and (octyl adi thiophene)		US-PGPUB	2003
350 BRS 2			US-PGPUB	2003
351 BRS 0	((427/\$3.cor.)) and (octyl adj thiophene)	USPAT;	US-PGPUB	2003
352 BRS 5	(sensor) and (octyl adj thiophene)	USPAT;	US-PGPUB	2003
353 BRS 2	((257/\$3.cor.) or (438/\$3.cor.)) and p30t	USPAT:	US-PGPUB	2003
354 BRS 5		USPAT	US-PGPUB	2003
355 BRS 3 356 BRS 3	(transistor) and p30t (transistor) and p\$1"30t"	USPAT	US-PGPUB	2003 2003
357 BRS 0	:(transistor) and p\$1 391	USPAT.	US-PGPUB	
358 BRS 0	(transistor) and pol\$1"3-octythiophene"	USPAI,	US-PGPUB	2003
359 BRS 6			US-PGPUB	.0000
360 BRS 7	i poly\$1"3-octylthiophene"			2003/
361 BRS 0	:(((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconduc	LISPAT.	LIS-PGPUR	2003/
362 BRS 39	(((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not (((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not (((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and thiophene) and (@ad<20010102) and octyl) not ((organic with semiconductor) and (organic wit			2003
363 BRS 2	((US-4862237-\$ or US-6452212-\$ or US-6433359-\$ or US-6326640-\$ or US-5329112-\$ or US-5892244-\$ or			
364 BRS 3	((US-4862237-\$ or US-6452212-\$ or US-6433359-\$ or US-6326640-\$ or US-5329112-\$ or US-5892244-\$ or	USPAT	US-PGPUR	FPO: 2003
365 BRS 0	("4021835"	USPAT.	US-PGPUB	2003
34 34 34 3 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1		USPAT	US-PGPUB	2003/
367 BRS 12	:("3-octylthiophene" and (misfet or mosfet or igfet or fet or transistor)) and (@ad<20010102)	USPAT	US-PGPUB	2003/
11366 BRS 1	5315129.pn		US-PGPUB	2003/
369 BRS 13	*3-octylthiophene* *3-octylthiophene* and (misfet or mosfet or idfet or fet or transistor)			IT: IBM 2003/
370 BRS 20	"3-octvithiophene" and (misfet or mosfet or iofet or fet or transistor)		US-PGPUB	2003/
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370 BRS 20		USPAT; US-PGPUB	2003
371 BRS 0	"poly(3-octylthiophene)" and (misfet or mosfet or infet or fet or transistor)	USPAT; US-PGPUB	2003
372 BRS 19	poly (3-octythiophene)" and (misfet or mosfet or igfet or fet or transistor)	USPAT; US-PGPUB	2003
373 BRS 8	poly (3-octylthiophene)* and (photo\$1sensitive or photo\$1sensitivity)	USPAT: US-PGPUB	2003.
374 BRS 10	*3-octylthiophene* and (photo\$1sensitive or photo\$1sensitivity) ((organic with (photo\$1transistor or (photo adj transistor)))) and ((@ad<20010102) or (@rlad<20010102))	USPAT; US-PGPUB	2003.
375 BRS 10	((organic with (photo\$1(ransistor or (photo ad (ransistor)))) and ((@ad<20010102) or (@nad<20010102))	USPAT, US-PGPUB	2003
376 BRS 37	(organic same (photo\$1transistor or (photo adi transistor))) (((organic same (photo\$1transistor or (photo adi transistor)))) and ((@ad<20010102) or (@rlad<20010102)	USPAT, US-PGPUB	2003.
377 BRS 0	((lorganic same (photo\$itransistor or (photo adj transistor)))) and ((@ad<20010102) or (@riad<20010102)	USPAT, US-PGPUB	2003
STE BKS 6	: "p3ot" and (photo\$1sensitive or photo\$1sensitivity) :((organic same (photo\$1transistor or (photo adi transistor)))) and ((@ad<20010102) or (@rlad<20010102))	USPAT, US-PGPUB	2003
	(topgame same (prioto) transistor or (prioto adjuransistor)))) and ((@ao<20010102)) or (@nao<20010102))	USPAT, US-PGPUB	2003
380 BRS 1	(photo\$1transistor or (photo adj transistor)) and "3-octylthiophene" ("3-octylthiophene" and (photo\$1sensitive or photo\$1sensitivity)) and ((@ad<20010102) or (@rlad<2001010	USPAT, US-PGPUB	2003
381 BRS 9	(3-octytimophene and (photo\$1sensitive of photo\$1sensitivity)) and ((@ad<20010102) of (@nau<2001010	USPAT, US-PGPUB	2003 2003
1302 DNS 30	"alkytthiophene" and (photo\$1sensitive or photo\$1sensitivity) (photo\$1transistor or (photo adj transistor))_and (("alkytthiophene" and (photo\$1sensitive or photo\$1sensitivi	LICENT LICE DODIES	2003
384 BRS 0	[Philoto-Finalisation of the formal state of the final state of the formal state of th	LICOAT LIC DODIE	2003
385 BRS 3	."alkyithiophene" same (photo\$1sensitive or photo\$1sensitivity) 	USPATI US-FORUD	2003
	"(((alkylthiophene" and (photo\$1sensitive or photo\$1sensitivity)) and ((@ad<20010102) or (@rlad<20010102):	LISPAT: LIS DODLIB	2003
			2003
700 BBS 16	(((misfet or mosfet or igfet or fet or transistor) and alkylthiophene) and ((@ad<20010102) or (@rlad<20010	LISDAT: LIS DODLIR	2003
789 BPC 15	((minister or moster or light or ret or manistror) and anythinophiene) and (((@au-20010102) or (@nau-20010101) ((@au-20010102) or (@nau-2001010101)	LISPAT: LIS DGDLIR	2003
300 BRS 6	(organic with (photo\$1transistor or (photo adj transistor))) (((((@ad<20010102) or (@rlad<20010102)) and (array with (position or motion))) and ((photo\$1transistor or	LISPAT: LIS-PGPLIR	2003
391 BRS 36	(((@ad<20010102) or (@riad<20010102)) and (array with (photo\$1transistor or (photo adj transistor)))) and	LISPAT: LIS-PGPLIR	2003
392 BRS 1	*20020084504* and position	USPAT: US-PGPUR	2003
393 BRS 17		USPAT: US-PGPUB	2003
394 BRS 21	(@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with (sensor or se	USPAT: US-PGPUB	2003/
395 BRS 0	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
396 BRS 24	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with bearn)) and		2003/
			2003/
398 BRS 13	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT: US-PGPUB	2003/
399 BRS 0	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	LICOAT LIC BOBLIS	2003/
400 BRS 0	:((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
401 BRS 9	:((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and		2003/
402 BRS 8	:((@ad<20010102_or @rlad<20010102)_and_((photo\$1transistor or (photo adj transistor))_with_beam)) and		2003/
403 BRS 8	((@ad<20010102_or @rlad<20010102)_and_((photo\$1transistor or (photo adi transistor))_with_beam)) and		2003/
	. ((((@ad<20010102)) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adi transistor)))) an	USPAT; US-PGPUB	2003/
405 BRS 1	((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
406 BRS 1	. (((@ad<20010102_or_@rlad<20010102)_and_((photo\$1transistor or (photo adj transistor))_with_beam)) and		2003/
407 BRS 0	:((@ad<20010102 or @rlad<20010102) and ((photo\$1transistor or (photo adj transistor)) with beam)) and	USPAT; US-PGPUB	2003/
408 BRS 1	. (((@ad<20010102, or @rlad<20010102), and ((photo\$1transistor or (photo adj transistor)), with beam)) and	USPAT; US-PGPUB	2003/
409 BRS 0	((photo\$1transistor or (photo adj transistor)) with (flexible adj substrate))	USPAT; US-PGPUB	2003/
410 BRS 1	; ((photo\$1transistor or (photo adi transistor)) same (flexible adi substrate))	USPAT; US-PGPUB	2003/
411 BRS 0	((((@ad<20010102)) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adi transistor)))) an	USPAT: US-PGPUB	2003/

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Type Hits		DBs	Time
411 BRS 0	((((@ad<20010102) or (@rlad<20010102)) and (array with (photo\$1transistor or (photo adj transistor)))) an	USPAT: US-PGPU	3 2003/
412 BRS 0	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010	USPAT: US-PGPU	3 2003/
	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010		
	((((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor))) and (@ad<2001010		
	(US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-\$ or US-6197663-\$ or U		
	(US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-\$ or US-6197663-\$ or U		
417 BRS 10 418 BRS 3	"3-octylthiophene" and (photo\$1sensitive or photo\$1sensitivity) "3-octylthiophene" and ((US-5986206-\$ or US-6512172-\$ or US-6429040-\$ or US-5670791-\$ or US-5347144-	HEDAT HE DODIN	3 2004/
419 BRS 1	: 3-octylthiophene" same (transistor or mosfet or misfet or fet))	HISDAT: HIS DOD!	3 2004/
420 BRS 1	"20020084504"	HSDAT: US DODIN	3 2004/
421 BRS 0	'20020084504'	HSPAT: HS-PGPH	3 2004/
422 BRS 4	"2002/0084504" ("3-octylthiophene" and (transistor or mosfet or misfet or fet).ab.)	LISPAT: LIS-PGPUI	3 2004/
423 BRS 8	("p3ot" and (transistor or mosfet or misfet or fet))	USPAT: US-PGPU	3 2004/
MADAS BRS 3	("n3ot" and (transistor or mosfet or misfet or fet))) not (("3-octylthiophene" and (transistor or mosfet or misfet	LISPAT: LIS-PGPUI	3 2004/
425 BRS 20	("3-octylthiophene" and (transistor or mosfet or misfet or fet))	USPAT: US-PGPUI	3 2004/
426 BRS 12	("3-octylthiophene" or "p3ot") and tft	USPAT: US-PGPUI	3 2004/
427 BRS 7	("3-octylthiophene" or "p3ot") and tft (("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT: US-PGPUI	3 2004/
1428 BRS 0	*Polv(3-octvlthiophene-2.5 divl)*	USPAT: US-PGPUI	3 :2004/
429 BRS 2	((("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT: US-PGPUI	3 2004/
430 BRS 18	(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and (tft or (((thin adi film) or thin\$1fi	USPAT: US-PGPUI	3 2004/0
	("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and (tft or (((thin adj film) or thin\$1fil	EPO; JPO; DERWI	ENT; IBM 2004/0
		USPAT: US-PGPUI	
433 BRS 27	("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and (tft or (((thin adi film) or thin\$1fil	USPAT; US-PGPUI	3 2004/0
	(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene or (poly adi octyl adi thiophene) or (p		3 2004/0
	((((photo\$1transistor or (photo adi transistor)) with ((position or motion) adi sensor))) and (@ad<2001010		
436 BRS 1	(((_((photo\$1transistor or (photo adj transistor))_with ((position or motion) adj sensor))) and (@ad<200101_	USPAT; US-PGPUI	3 2004/0
437 BRS 4	(((((photo\$1transistor or (photo adi transistor)) same ((position or motion) adi sensor))) and (@ad<20010	USPAT; US-PGPUI	3 2004/0
	((photo\$1transistor or (photo adi transistor)) with ((position or motion) adi sensor)) and ((((photo\$1transist		
439 BRS 4	((photo\$1transistor or (photo adj transistor)) same_((position or motion) adj sensor)) and ((((photo\$1transi	USPAT; US-PGPUI	3 :2004/
440 BRS 14	((photo\$1transistor or (photo adj transistor)) with imager) and (@ad<20010102 or @rlad<20010102)	USPAT; US-PGPUI	3 2004/0
441 BRS 22	semiconductor and (flexible with imager) (semiconductor and (flexible with imager)) and (@ad<20010102 or @rlad<20010102)	USPAT, US-PGPUI	3 2004/0
442 BRS 17	(Semiconductor and (nexible with inager)) and (@ao<2001002 or @nad<20010102)	USPAT: US-PGPUI USPAT: US-PGPUI	
443 BRS 2 444 BRS 28	(brittle same_imager) and_(@ad<20010102_or_@rlad<20010102) (stress with_imager) and_(@ad<20010102_or_@rlad<20010102)	USPAT, US-PGPUI	3 2004/0
445 BRS 4	(stress with imager) and (@ad<20010102 or @rlad<20010102) ((flexible adi substrate) same imager) and (@ad<20010102 or @rlad<20010102)	LICENT LICE DOCUM	3 2004/0
446 BRS 7	((flexible adj substrate) and (imager ab.)) and (@ad<20010102 or @rlad<20010102)	LISBAT: LIS DODILI	3 2004/0
447 BRS 6	(cmos adj imager) and (@ad<20010102 or @riad<20010102) and (economical with (manufacturing or proc	HISDAT- HIS DODIN	3 2004/0
	(cmos adjimage) and (@ad<20010102 or @rlad<20010102) and (economical with (manufacturing or proce		
		USPAT: US-PGPU	
		USPAT: US-PGPUI	
	(("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and ((organic		2004/0
452 BRS 6	("p3ot" or "p3ot" or (octvl adi thiopene)) and tft	USPAT: US-PGPUI	2004/
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	BRS 7	:((*3-octy/thiophene* or *p3ot* or (octyl adi thiophene) or octyl\$1thiophene) and tft) not ((*3-octylthiophene* or *	USPAT:	US-PGPUB	2004/01/0
	BRS 0	*Poly(3-octylthiophene-2.5 diyl)*	USPAT:	US-PGPUB	2004/01/0
	BRS 2	"Poly(3-octylthiophene-2,5 diyl)" [(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and tft) not (("3-octylthiophene" or "	USPAT:	US-PGPUB	2004/01/0
	8BRS :18	:(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octylathiophene) and (tit or (((thin adi film) or thinathi	USPAI:	US-PGPUB	2004/01/0
	BRS 0	"3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and (tft or (((thin adj film) or thin\$1fil	EPO: JP	O; DERWENT; IBM	2004/01/0
432	BRS 1	:("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and (6331356.pn.)	USPAT:	US-PGPUB	2004/01/0
433	BRS 27	("3-octythiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and (tft or (((thin adj film) or thin\$1fil	USPAT;	US-PGPUB	2004/01/0
434	BRS 27	(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene or (poly adi octyl adi thiophene) or (p	USPAT:	US-PGPUB	2004/01/0
		((((photo\$1transistor or (photo adi transistor)) with ((position or motion) adi sensor).)) and (@ad<2001010.	USPAT:	US-PGPUB	2004/01/1
	BRS 1	(((((photo\$1transistor or (photo adi transistor)) with ((position or motion) adi sensor))) and (@ad<200101	USPAT;	US-PGPUB	2004/01/1
		(((((photo\$1transistor or (photo adj transistor)) same ((position or motion) adj sensor))) and (@ad<20010	USPAT;	US-PGPUB	2004/01/1
	BRS 1	((photo\$1transistor or (photo adj transistor)) with ((position or motion) adj sensor)) and ((((photo\$1transist			2004/01/1
	BRS 4	(photo\$1transistor or (photo adj transistor)) same ((position or motion) adj sensor).) and (((photo\$1transi	USPAT;	US-PGPUB	2004/01/1
	BRS 14	((photo\$1transistor or (photo adi transistor)) with imager) and (@ad<20010102 or @rlad<20010102)	USPAT:	US-PGPUB	2004/01/
	BRS 22	semiconductor and (flexible with imager)	USPAT:	US-PGPUB	2004/01/
	BRS 17	semiconductor and (flexible with imager) (semiconductor and (flexible with imager)) and (@ad<20010102 or @rlad<20010102) (brittle same imager) and (@ad<20010102 or @rlad<20010102)	USPAT:	US-PGPUB	2004/01/
	BRS 2	(brittle same_imager) and (@ad<20010102_or @rlad<20010102)	USPAT	US-PGPUB	2004/01/
	BRS 28	(stress with imager) and (@ad<20010102 or @rlad<20010102)	USPAT.	US-PGPUB	2004/01/
11413	BRS 4	((flexible adj substrate) same imager) and (@ad<20010102 or @riad<20010102)	USPAT.	US-PGPUB US-PGPUB	2004/01/
	BRS 7				2004/01/
	BRS 6 BRS 17	(crnos adj imager) and (@ad<20010102 or @rlad<20010102) and (economical with (manufacturing or proc (crnos adj image) and (@ad<20010102 or @rlad<20010102) and (economical with (manufacturing or proce	LICDAT:	US-FGFUB	2004/01/
				US-PGPUB	2004/01/
					2004/01/
	DRO E	"20020084504" and gain (("p3ot" or "p3ot" or "p3at" or (alky) adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and ((organic	LICOAT	IIS DODIID	2004/01/
32.	BRS 5 BRS 6		LICDAT	US-PGPUB	2004/01/
	BRS 8	("p3ot" or "p3ot" or (octyl adj thiopene)) and tft ("p3ot" or "p3ot" or (octyl adj thiopene)) and (tft or (thin adj film adj transistor) or (thin\$1film adj transistor))			2004/01/
	BRS 8	("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and tft	LISPAT		2004/01/
	DRS 13	("p3ot" or "p3ot" or "p3at" or (alkyl adj thiopene) or (octyl adj thiopene) or (hexyl adj thiopene)) and (tft or (thi			2004/01/
456	BPC 10	"3-oct of post or post or (oct 4 ad thiophers) or oct 4\$1thiophers) and th	LISPAT	LIS-PGPLIR	2004/01/
124	BRS 1	("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and tft (brittle with imager) and (@ad<20010102 or @rlad<20010102)	LISPAT	US-PGPUB	2004/01/
258	BRS 19	:("3-octylthionhene" or "n3ot" or (octyl adi thionhene) or octyl\$1thionhene) and tft	USPAT	US-PGPUB	2004/01/
250	BRS 12	("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and tft (("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and tft) and (@ad<20010102 or	USPAT	US-PGPUB	2004/01/
460	BRS 31	("3-octylthiophene" or "p3ot" or (octyl adj thiophene) or octyl\$1thiophene) and ((thin\$1film or (thin adj film)) wit	USPAT:	US-PGPUB	2004/01/
461	BRS 16	(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and ((thin\$1film or (thin adi film)) wi	USPAT:	US-PGPUB	2004/01/
		:(("3-octylthiophene" or "p3ot" or (octyl adi thiophene) or octyl\$1thiophene) and ((thin\$1film or (thin adi film)) w			2004/01/
		(("p3at" or (alkyl adj thiophene) or (hexyl adj thiophene)) and ((thin\$1film or (thin adj film)) with (transistor or			2004/01/
		((*p3at* or (alkyl adj thiophene) or (hexyl adj thiophene)) and ((thin\$1film or (thin adj film)) with (transistor or			2004/01/
465	BRS 38	("p3at" or (alkyl adi thiophene) or (hexyl adi thiophene)) and ((thin\$1film or (thin adi film)) with (transistor or	USPAT:	US-PGPUB	2004/01/
466	BRS 14	*5659181* and (@ad<20010102 or @rlad<20010102)	USPAT;	US-PGPUB	2004/01/
467	BRS 14	"5659181" and (@ad<20010102 or @rlad<20010102) ("5659181" and (@ad<20010102 or @rlad<20010102)) and ((thin\$1film or (thin adj film)) with (transistor o	USPAT;	US-PGPUB	2004/01/2
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